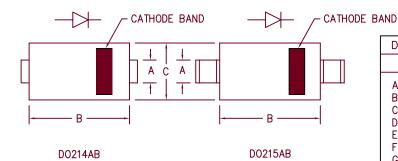
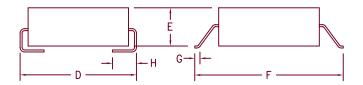
5 Amp Schottky Rectifier HSM580 — HSM5100



Dim.	. Inches	ches Millimeter				
	Minimum	Maximum	Minimum	Maximum	Notes	
Α	.117	.123	2.97	3.12		
В	.260	.280	6.60	7.11		
С	.220	.245	5.59	6.22		
D	.307	.322	7.80	8.18		
Ε	.075	.095	1.91	2.41		
F	.380	.400	9.65	10.16		
G	.025	.040	.640	1.02		
Н	.030	.060	.760	1.52		



Microsemi Catalog Number	Industry Part Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage
HSM580* HSM590* HSM5100*	SK58L SK510L	80V 90V 100V	80V 90V 100V

* Add Suffix J for J Lead or G for Gull Wing Lead Configuration

- Schottky Barrier Rectifier
- Guard Ring Protection
- High surge capacity
- •VRRm 80 to 100 volts
- Surface mount packages

Electrical Characteristics

Average forward current
Maximum surge current
Max peak forward voltage
Max peak forward voltage
Max peak reverse current
Typical junction capacitance

I F(AV) 5.0 Amps I FSM 200 Amps V FM .60 Volts V FM .80 Volts I RM 250 µA CJ 280 pF Square wave, $^{T}L = 95^{\circ}C$, $^{R}\Theta JL = 22^{\circ}C/W$ 8.3ms, half sine, $^{T}J = 175^{\circ}C$ $^{I}FM = 1A$; $^{T}J = 25^{\circ}C^{\circ}$ $^{I}FM = 5A$; $^{T}J = 25^{\circ}C^{\circ}$ ^{V}RRM , $^{T}J = 25^{\circ}C$ $^{V}R = 5.0V$, $^{T}J = 25^{\circ}C$

*Pulse test: Pulse width 300 µsec, Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range Operating junction temp range Maximum thermal resistance Weight TSTG TJ ROJL

-55°C to 175°C -55°C to 175°C 22°C/W Junction to lead

.008 ounces (.22 grams) typical



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HSM580 - HSM5100

Figure 1 Typical Forward Characteristics

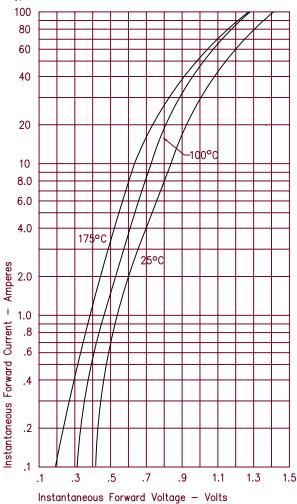


Figure 2 Typical Reverse Characteristics

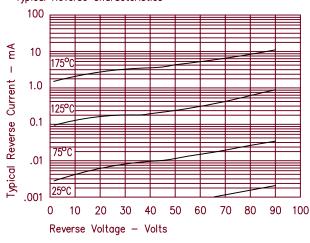


Figure 3 Typical Junction Capacitance

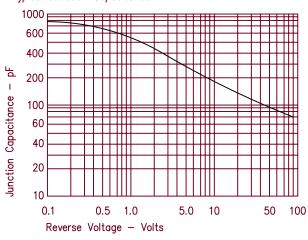


Figure 4
Forward Current Derating

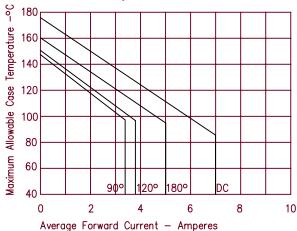
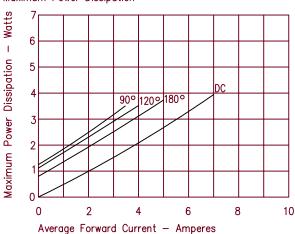
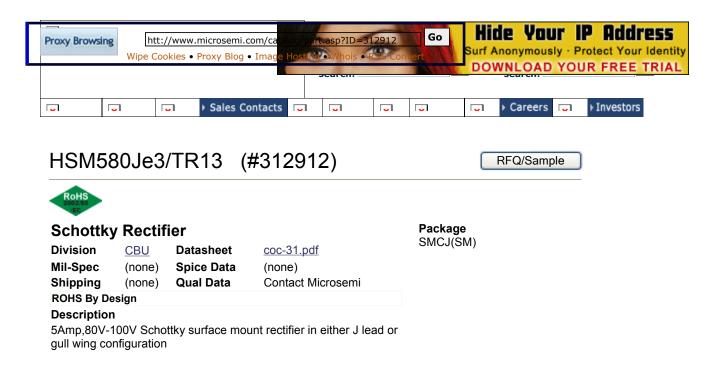


Figure 5 Maximum Power Dissipation





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